Product data sheet

1. General description

PNP low V_{CEsat} double transistor in a SOT666 ultra small and flat lead Surface-Mounted Device (SMD) plastic package.

NPN complement: PBSS2515VS

2. Features and benefits

- 300 mW total power dissipation
- Very small 1.6 x 1.2 mm ultra thin package
- Self alignment during soldering due to straight leads
- Low collector-emitter saturation voltage
- High current capability
- Improved thermal behavior due to flat leads
- Replaces two SC75/SC89 packaged low V_{CEsat} transistors on same PCB area
- Reduces required PCB area
- Reduced pick and place costs

3. Applications

- General purpose switching and muting
- Low frequency driver circuits
- · Audio frequency general purpose amplifier applications
- · Battery driven equipment (mobile phones, video cameras and hand-held devices)

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per transistor						
V _{CEO}	collector-emitter voltage	open base	-	-	-15	V
I _C	collector current		-	-	-500	mA
h _{FE}	DC current gain	$V_{CE} = -2 \text{ V; } I_{C} = -10 \text{ mA; } T_{amb} = 25 \text{ °C}$	200	-	-	



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5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	E1	emitter TR1	6 5 4	C1 B2 E2
2	B1	base TR1		
3	C2	collector TR2		(TR1) TR2)
4	E2	emitter TR2	0	
5	B2	base TR2	1 2 3	I I I E1 B1 C2
6	C1	collector TR1	SOT666	sym138

6. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
PBSS3515VS	SOT666	plastic, surface-mounted package; 6 leads; 0.5 mm pitch; 1.6 mm x 1.2 mm x 0.55 mm body	<u>SOT666</u>		

7. Marking

Table 4. Marking codes

Type number	Marking code
PBSS3515VS	35

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transiste	or					
V _{CBO}	collector-base voltage	open emitter		-	-15	V
V _{CEO}	collector-emitter voltage	open base		-	-15	V
V _{EBO}	emitter-base voltage	open collector		-	-6	V
I _C	collector current			-	-500	mA
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	-1	Α
I _{BM}	peak base current	-		-	-100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	200	mW
Per device				<u> </u>	-	
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	300	mW
T _j	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	150	°C
T _{stg}	storage temperature			-65	150	°C

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

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9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	416	K/W

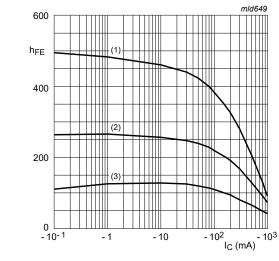
^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per transist	tor			'		'
I _{CBO}	collector-base cut-off	V _{CB} = -15 V; I _E = 0 A; T _{amb} = 25 °C	-	-	-100	nA
	current	V _{CB} = -15 V; I _E = 0 A; T _j = 150 °C	-	-	-50	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; I_{C} = 0 \text{ A}; T_{amb} = 25 ^{\circ}\text{C}$	-	-	-100	nA
h _{FE}	DC current gain	V _{CE} = -2 V; I _C = -10 mA; T _{amb} = 25 °C	200	-	-	
		V_{CE} = -2 V; I_{C} = -100 mA; pulsed; $t_{p} \le$ 300 μs; $δ \le 0.02$; T_{amb} = 25 °C	150	-	-	
		V_{CE} = -2 V; I_{C} = -500 mA; pulsed; $t_{p} \le$ 300 μs; $δ \le 0.02$; T_{amb} = 25 °C	90	-	-	
V _{CEsat}	collector-emitter	I_C = -10 mA; I_B = -0.5 mA; T_{amb} = 25 °C	-	-	-25	mV
	saturation voltage	I_C = -200 mA; I_B = -10 mA; T_{amb} = 25 °C	-	-	-150	mV
		I_C = -500 mA; I_B = -50 mA; pulsed; $t_p \le$	-	-	-250	mV
R _{CEsat}	collector-emitter saturation resistance	300 μs; δ ≤ 0.02; T _{amb} = 25 °C	-	300	500	mΩ
V_{BEsat}	base-emitter saturation voltage		-	-	-1.1	V
V_{BEon}	base-emitter turn-on voltage	V_{CE} = -2 V; I_{C} = -100 mA; pulsed; $t_{p} \le$ 300 μs; $δ \le$ 0.02; T_{amb} = 25 °C	-	-	-0.9	V
f _T	transition frequency	V_{CE} = -5 V; I_{C} = -100 mA; f = 100 MHz; T_{amb} = 25 °C	100	280	-	MHz
C _c	collector capacitance	V _{CB} = -10 V; I _E = 0 A; i _e = 0 A; f = 1 MHz; T _{amb} = 25 °C	-	-	10	pF

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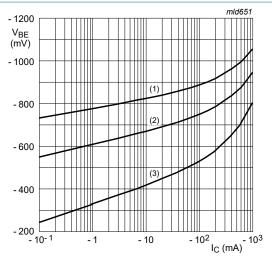


$$V_{CE} = -2 V$$

$$(1) T_{amb} = 150 °($$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 1. DC current gain as a function of collector current; typical values

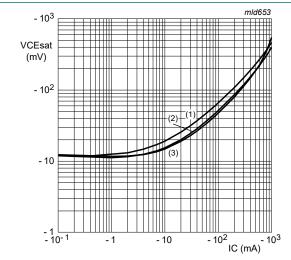


$$V_{CE} = -2 V$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 2. Base-emitter voltage as a function of collector current; typical values



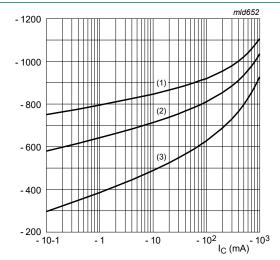
$$I_{\rm C}/I_{\rm B}=20$$

(1)
$$T_{amb}$$
 = 150 °C

$$(2) T_{amb} = 25 °C$$

(3)
$$T_{amb} = -55 \,^{\circ}C$$

Fig. 3. Collector-emitter saturation voltage as a function of collector current; typical values



$$I_C/I_B = 20$$

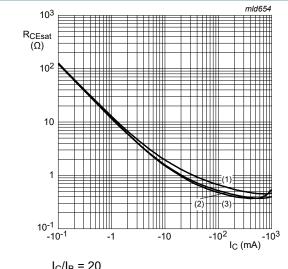
(1)
$$T_{amb} = 150 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

$$(3) T_{amb} = -55 °C$$

Fig. 4. Base-emitter saturation voltage as a function of collector current; typical values

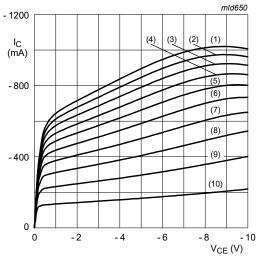
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 $I_{\rm C}/I_{\rm B} = 20$

(1) T_{amb} = 150 °C (2) T_{amb} = 25 °C (3) T_{amb} = -55 °C

Equivalent on-resistance as a function of Fig. 5. collector current; typical values



 T_{amb} = 25 °C

(1) $I_B = -7 \text{ mA}$

(2) $I_B = -6.3 \text{ mA}$ (3) $I_B = -5.6 \text{ mA}$ (4) $I_B = -4.9 \text{ mA}$ (5) $I_B = -4.2 \text{ mA}$

 $(6) I_B = -3.5 \text{ mA}$

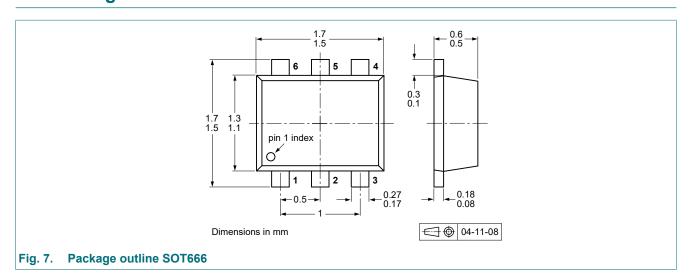
 $(7) I_B = -2.8 \text{ mA}$ $(8) I_B = -2.1 \text{ mA}$

(9) $I_B = -1.4 \text{ mA}$

 $(10) I_B = -0.7 \text{ mA}$

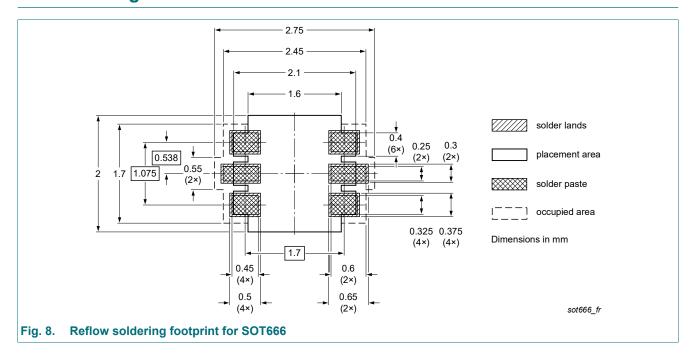
Fig. 6. Collector current as a function of collectoremitter voltage; typical values

11. Package outline



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12. Soldering



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13. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
PBSS3515VS v.3	20221228	Product data sheet	-	PBSS3515VS v.2			
Modifications:	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. Product(s) changed to non-automotive qualification. 						
PBSS3515VS v.2	20041223	Product data sheet	-	PBSS3515VS v.1			
PBSS3515VS v.1	20011107	Product data sheet	-	-			

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14. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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